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Pauli Blockade in Silicon Quantum Dots with Spin-Orbit Control

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Quantum computation relies on accurate measurements of qubits not only for reading the output of the calculation, but also to perform error correction. Most proposed scalable silicon architectures utilize Pauli blockade of triplet states for spin-to-charge conversion. In recent experiments there have been instances when instead of conventional triplet blockade readout, Pauli blockade is sustained only between parallel spin configurations, with \( |T_0\rangle \) relaxing quickly to the singlet state and leaving \( |T_+\rangle \) and \( |T_-\rangle \) states blockaded—which we call parity readout. Both types of blockade can be used for readout in quantum computing, but it is crucial to maximize the fidelity and understand in which regime the system operates. We devise and perform an experiment in which the crossover between parity and singlet-triplet readout can be identified by investigating the underlying physics of the \( |T_0\rangle \) relaxation rate. This rate is tunable over 4 orders of magnitude by controlling the Zeeman energy difference between the dots induced by spin-orbit coupling, which in turn depends on the direction of the applied magnetic field. We suggest a theoretical model incorporating charge noise and relaxation effects that explains quantitatively our results. Investigating the model both analytically and numerically, we identify strategies to obtain on demand either singlet-triplet or parity readout consistently across large arrays of dots. We also discuss how parity readout can be used to perform full two-qubit state tomography and its impact on quantum error-detection schemes in large-scale silicon quantum computers.

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I. INTRODUCTION

The recent demonstration of large-scale quantum computation [1] has opened the door to the exploration of near-term applications of noisy, intermediate-scale devices. This, however, does not change the long-term vision wherein quantum error correction is essential to achieve the full advantages of quantum computing [2]. Theoretical estimates predict a large overhead in terms of the number of required physical qubits for this task [3]. As quantum-computing technologies progress from demonstrations to industrial platforms, silicon-based architectures become increasingly competitive due to the possibility of mass production of few-nanometer-sized qubit systems [4–7]. Such qubits have high control fidelity at the one- [8–13] and two-qubit [14–16] levels.

Error-correcting codes require a highly connected network of qubits [17], setting topological constraints on large-scale designs. Pauli spin blockade can be employed to readout the state of silicon qubits [4,5,18], which removes the need for reservoirs near the dots, and loosens design constrains. Recent experiments have validated the operation of single spin qubits together with Pauli-blockade readout in silicon-metal-oxide-semiconductor (SiMOS) quantum dots [19–21]. In some experiments [21], this singlet-triplet readout has not been complete. The non-polarized triplet \( T_0 \) state in these experiments decays faster than the measurement bandwidth limits, leading to a parity readout [22] where the blockade is selective to whether...
the total parity of the spins is odd or even. This result is not consistent for all silicon devices of the same type, since some silicon samples preserve singlet-triplet blockade \cite{19,20}, raising the question: what conditions give rise to parity readout? This question becomes especially important in large arrays of dots, since some readout pairs might end up being in parity and some in singlet-triplet readout mode. Additionally, qubit encoded based on pairs of spins in which the logical 0 and 1 states are represented by singlets and triplets, respectively, cannot be read out using parity readout \cite{23}.

Here, we explore a device that operates at the interface of the parity and singlet-triplet readout, allowing us to study the origin of the $T_0$ blockade lifting. We can tune the $T_0$ blockade lifting rate by 4 orders of magnitude by controlling Zeeman energy difference, which is tuned in our system by varying the angle of the external magnetic field relative to the crystal lattice, since the Zeeman energy difference is dominated by spin-orbit interaction \cite{24}. Incorporating this observation, we use perturbation theory to model the blockade time in the system both analytically \cite{25} and computationally. We investigate both charge relaxation and dephasing as the mechanisms for $T_0$ blockade lifting. We find that both models fit qualitatively the experimental data, but the fitted charge-dephasing time is more reasonable than the fitted relaxation time, suggesting a different type of underlying mechanism in silicon than in GaAs \cite{23}.

These results are an important tool to be able to understand how to tune the readout from parity to singlet-triplet and vice versa. Due to the statistical variability of Zeeman energies in an array of dots, gate control of tunnel rates between each pair of dots is necessary. The detuning is limited by valley or orbital excitations. Moreover, the magnetic field angle can be set to point along the device in Ref. \cite{21}, where due to the micromagnet only the parity readout was possible. Left and right dots are formed under gates $G1$ and $G3$ (made of palladium), respectively, and are laterally surrounded by the confinement barrier gate (CB). Figure 1(b) depicts our operating regime near the (1,3)-(0,4) charge transition (the numbers in brackets represent the total amount of electrons in the left and right dots, respectively). The two lowest energy electrons in the right dot lie in the lower valley state, which is separated from the upper valley state by a large enough excitation energy to be easily discernible experimentally (typically larger than 0.1 meV). This results in a spin-0 closed shell that does not impact the spin dynamics of the two extra electrons. For simplicity, we ignore the two lowest energy electrons in the right dot and refer to the possible charge configurations as (1,1) and (0,2) later in the text.

The details of the measurement scheme are illustrated in Fig. 1(c). The experiment starts in the (0,1) charge state. An electron is then loaded into the right dot, leading to a singlet ground state $|S(0,2)\rangle$. Then, the detuning between the dots is changed across the (0,2) $\rightarrow$ (1,1) transition, allowing one electron to tunnel into the left dot. The initial spin state depends on the ramp rate going from (0,2) to (1,1), which determines whether the energy anticrossings with $|T_-(1,1)\rangle$ or $|S(1,1)\rangle$ are swept adiabatically or not. Following this, the electrons are manipulated in different ways, either by electron spin resonance or detuning control. Finally, the resulting two-spin state would normally be measured by returning to the (0,2) charge configuration near the transition from (1,1)—the readout configuration in the Pauli-blockaded region \cite{27}. This way, only the spin singlet would be able to tunnel back into the (0,2) state; therefore, the charge state of the double dot would reflect what the spin state was at the time of the measurement. This simplified picture, as we show next, only holds immediately after the dot is brought to the readout configuration.

We initialize the $|T_0\rangle$ state with 97% initialization fidelity by preparing a singlet state and consequently waiting for half the period of the spin-orbit-induced singlet-triplet oscillations. The details of the experiment are explained in the Supplemental material in Ref. \cite{20}. Alternatively, we also initialize $|T_-\rangle$ states by adiabatically preparing a $|\uparrow\downarrow\rangle$ state and pulsing a microwave in resonance with the transition in the left dot to $|\downarrow\downarrow\rangle$, which can be distinguished from the transition in the right dot through spin-orbit interaction (see Ref. \cite{24} for more details). This initialization has a limited visibility of around 30% because the electron spin resonance (ESR) antenna in the present device is defective.

II. EXPERIMENTS ON RATE OF BLOCKADE LIFTING AND G-FACTOR DIFFERENCE

Figure 1(a) shows the scanning electron microscope image of a device nominally identical to the one used in the experiments, together with the schematic cross section. This device accumulates electrons in the isotopically purified silicon slab (800 ppm residual $^{29}$Si \cite{26}) and has been used in experiments reported in Ref. \cite{20}. This device can be operated in singlet-triplet readout mode in contrast to the device in Ref. \cite{21}, where due to the micromagnet only the parity readout was possible. Left and right dots are formed under gates $G1$ and $G3$ (made of palladium), respectively, and are laterally surrounded by the confinement barrier gate (CB). Figure 1(b) depicts our operating regime near the (1,3)-(0,4) charge transition (the numbers in brackets represent the total amount of electrons in the left and right dots, respectively). The two lowest energy electrons in the right dot lie in the lower valley state, which is separated from the upper valley state by a large enough excitation energy to be easily discernible experimentally (typically larger than 0.1 meV). This results in a spin-0 closed shell that does not impact the spin dynamics of the two extra electrons. For simplicity, we ignore the two lowest energy electrons in the right dot and refer to the possible charge configurations as (1,1) and (0,2) later in the text.

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To study the lifetime of the Pauli blockade of the spin triplet configurations, we use latched singlet-triplet readout [19,20,28,29]. This process is schematically illustrated in Fig. 1(c). After some wait time $\tau$ in the (0,2) readout configuration, we move to the latched readout region within the (1,2) configuration space. Latching detects the difference in initial charge state, because of the slow loading of an electron to the left dot. The $|S(0,2)\rangle$ state will stay in the (0,2) configuration and the blockaded triplet states will allow the fast transition from the (1,1) into the (1,2) charge state. Now the charge state represents a mapping of the spin states at the moment when the latching pulse occurred. A slow charge sensing step will no longer compromise the conclusion regarding the spin state at the readout point. In summary, we end up with three possible readout schemes: latched Pauli spin blockade, singlet-triplet readout and parity readout. The former, latched readout, is not scalable but is used as a tool to investigate the other two readout mechanisms.

During the wait time in the Pauli-blockade region, all triplet states will eventually decay to the ground state $|S(0,2)\rangle$. We observe that this rate is different for different
triplet states, as shown in Fig. 1(d). The odd-parity triplet |0⟩ decays in roughly 200 μs and the |T−⟩ decays in 5 ms. We mention, without showing here, that the |T+⟩ configuration also outlasts the |0⟩ decay by orders of magnitude (see Ref. [21] for further evidence). If the charge sensor (a continuous current single electron transistor in our case) requires a data-acquisition time between these two blockade-lifting time scales, we do not distinguish between the two odd-parity spin configurations (|S⟩ and |0⟩), but we do distinguish between these and the even-parity configurations (|T ±⟩). We call this a parity readout. This indicates that the physical mechanism for triplet blockade lifting is different between the even-parity triplets and |0⟩.

We describe our hypothesis. Even-parity triplet states require a spin-flip process accompanied by the emission of a phonon in order to relax into the singlet ground state—a process that is very slow in silicon [30]. On the other hand, the triplet |0⟩ and the singlet |S⟩ belong to the same subspace spanned by the |↑ ↑⟩, |↓ ↓⟩ states, which are approximately the system eigenstates in the (1,1) charge state, in the presence of a substantial difference in g factor between the dots (see below). The g-factor difference induces a fast oscillation between |0⟩ and |S⟩. While at the readout position, the wavefunction component that evolves into the singlet |S⟩ state rapidly oscillates between that and the singlet |0⟩ state due to the fast interdot tunnel rate. Charge dephasing and phonon-mediated relaxation damp these oscillations, which results in a steady state in which both electrons eventually are found in the (0,2) state. This is made clearer in Fig. 1(e), which shows a schematic energy diagram with the |0⟩ and |S⟩ oscillations, mediated through the Zeeman energy difference, and the decay into the |0⟩ state.

The S−T mixing is caused by the difference in Zeeman energies ΔEZ between the electrons in each dot. Since our device is fabricated on enriched 28Si, the Overhauser magnetic field is minimal and is not the main cause for ΔEZ (as confirmed a posteriori). Additionally, no magnetic materials are used for the metal stack and there is no Meissner effect since the gates are not superconducting. Therefore, ΔEZ is mostly determined by the spatial variations of the effective Landé g factor due to the spin-orbit coupling induced by the interface. Under this approximation, we have ΔEZ = gμBB/ℏ, where the difference in g factors between the two quantum dots is gμB is the Bohr magneton constant, and B is the magnitude of the magnetic field, where B = 600 mT for all experiments. These spin-orbit effects include a large Dresselhaus component, which can be controlled by the direction of the external magnetic field with regard to the silicon lattice (the presence of an interface breaks the inversion symmetry of the lattice) [24,31]. We use this controllability to correlate the blockade rate and the difference in Zeeman energies.

Firstly, we repeat the analysis described in Fig. 1(d) for all magnetic field angles in the plane of the device. Figure 2(a) shows the extracted rate of blockade lifting, Γ, for |0⟩ as red squares, which changes by 3 to 4 orders of magnitude. Next, the measurement of ΔEZ is carried out using two methods, with results shown in Fig. 2(b). One method is to use ESR to rotate a single spin in one of the dots. This is accomplished by initialising |↓↑⟩ by ramping adiabatically through the avoided crossing between |↓↑⟩ and |↑↓⟩ represented Fig. 2(c). Then, a microwave pulse is applied using the ESR antenna, which, at resonance frequencies fESR1 and fESR2, may rotate |↓↑⟩ to |↑↓⟩ and |↑↓⟩ to |↓↑⟩, respectively [see Fig. 2(c)]. Returning to the positive detuning ε configuration, the probability of a successful return to (0,2) depends whether the ESR pulse is in resonance with one of the transitions. The frequencies that are resonant show a dip in the return probability plotted in Fig. 2(d). The difference in these two frequencies gives approximately ΔEZ in the region where ΔEZ ≳ J, where J is the energy splitting between |0⟩ and |S⟩.

The other method to measure ΔEZ is to use singlet-triplet oscillations, where the spins are left to oscillate between the |S⟩ state and the |0⟩ states with frequency ΔEZ. To enable this oscillation, the state needs to be initialized in a |S⟩ state. Referring back to Fig. 2(c), we now ramp quickly through the (0,2)-(1,1) anticrossing, diabatically with respect to the Zeeman splitting differences, but still slowly with comparison to the tunnel rates so that the electrons always end up in the |S⟩ configuration. The oscillations initiate immediately after the condition ΔEZ ≳ J is met. Figure 2(e) shows the S−T oscillations as a function of magnetic field angle and the dwell time spent at the (1,1) configuration.

The extracted ΔEZ data for both of these methods, shown in Fig. 2(b), are in excellent agreement. Comparing the rate of blockade lifting and the Zeeman energies in Figs. 2(a) and 2(b), it is obvious that Γ increases as ΔEZ increases. When ΔEZ reaches a minimum at a magnetic field angle of −20 and 100°, there is a minimum in Γ at −30 and 105°. The small deviation is possibly due to Stark shift—ΔEZ is measured deep in the (1,1) regime, while Γ is determined at the readout point, where (0,2) is the charge ground state.

### III. NONUNITARY PROCESSES, PREDICTING BLOCKADE RATE

The numerical model is based on the Lindbladian form of the master equation [32,33] to allow for the implementation of Markovian noise, details can be found in the appendix. In this model, an operator is chosen to model the
FIG. 2. Correlation between Zeeman energy difference and the rate of lifting the triplet blockade. (a) The rate of lifting the triplet blockade (red squares) extracted from decay plots similar to Fig. 1(d) and is plotted as a function of in-plane magnetic field angle for \( B = 600 \) mT. (b) The difference in Zeeman energies plotted as a function of in-plane magnetic field angle, experimentally determined with two different methods, ESR (blue squares) and \( S - T_0 \) oscillations (green squares). (c) The energy diagram of a double-dot system as a function of detuning, showing schematically the initialization and control strategy for each of the methods presented in (b) to find the Zeeman energies. The arrow shows the fast, diabatic plunge into \((1,1)\), which initializes into \( |S(1,1)\rangle \) and allows for observation of \( S - T_0 \) oscillations. The two frequencies \( f_{\text{ESR1}} \) and \( f_{\text{ESR2}} \) in (c) are shown as dips in (d), which are the individual resonance frequencies of the electron spins in each dot. (e) The \( S - T_0 \) oscillations as a function of dwell time and in-plane magnetic field angle.

impact of the environment on the quantum system—either a dephasing channel, which is a consequence of charge noise, or a phonon-mediated relaxation channel.

The charge-dephasing noise model describes fluctuations in the detuning \( \epsilon \) due to charge fluctuations and how it impacts the energy separation between \((1,1)\) and \((0,2)\) states. In our model, noise in the tunnel rate is not considered because we expect the detuning noise to be the most significant given that it is caused by the dipole component of any far-away fluctuators, while the tunnel rate noise is caused by the quadrupole moment [34]. That said, the quadrupole stray fields may couple exponentially to the tunnel rate, so it is hard to determine without further experiments what would be the leading cause of charge dephasing. We do expect that our results are qualitatively preserved even in the presence of tunnel rate noise, but the Lindbladian model might differ in that case. Furthermore, the dependence of the \( T_2 \) parameter on the target detuning \( \epsilon \) is not included, which is a good approximation for \( \epsilon \gg \tau \).

Dephasing between spin states in the \((1,1)\) configuration due to fluctuations of \( \Delta E_Z \) occur at the order of hundreds of kHz. This is much slower than the scale of noise we are studying here. For the relaxation process, some dependence of \( T_1 \) on detuning is also expected [35], but we do not include that information in our analysis.

We specifically study the time evolution of the density operator when the initial state is a pure \( |T_0\rangle \) state \( \hat{\rho}(t = 0) = |T_0\rangle \langle T_0| \). A few examples are shown in Fig. 3(a) for the case of a dephasing channel with charge coherence time \( T_2^{\text{charge}} \). It is clear from these plots that there is an exponential damping of the \( T_0 - S \) oscillations, which is marked by red dashed lines showing a fitting curve of \( A e^{-t/T_2^{\text{blockade}}} + B \), which is used to extract \( T_2^{\text{blockade}} \) from simulations. The evolution of the \( |T_0\rangle \) state shows the oscillations between itself and \( |S(1,1)\rangle \) becoming damped over time. The dephasing term damps the oscillation until it has reached a fully mixed state. In principle, the model would also describe the overdamped single-shot tunneling across the double dot. In the example given in Fig. 3(a) the \( |T_0\rangle \) probability saturates at a value of 1/3. This is
because the dephasing channel mixes the three states at equal weights. This is an artifact of a model that only considers dephasing. When relaxation is taken into account, eventually the state is fully polarized in the \( |S(0, 2)\rangle \) state.

Due to the use of a simplified Markovian model, the two effects are not captured together. Instead, the relaxation channel is investigated independently to the dephasing, where \( \Gamma_{\text{blockade}} \) values are extracted in a similar way to that described using dephasing channels.

Since neither the charge relaxation or the charge-dephasing times are known \emph{a priori} for this device, we study the blockade rate as a function of both parameters in the plots shown in Fig. 3(b). The value of the tunnel coupling at this operation configuration is determined to be \( t \approx 3 \text{ GHz} \) using a spin-funnel experiment [36]. The detuning of \( \varepsilon \approx 140 \text{ GHz} \) is extracted from the operation point and known lever arm (measured using magnetospectroscopy). The Zeeman energy difference varies between \( \Delta E_Z \approx 0 - 20 \text{ MHz} \) [see also Fig. 2(b)].


IV. CHARGE RELAXATION AND DEPHASING TIMES

Experimentally, there is a corresponding \( \Gamma_{\text{blockade}} \) value for each \( \Delta E_Z \). [The horizontal black dashed lines in Fig. 3(b) indicate these.] We analyze four values of \( \Delta E_Z \) and how they lead to blockade lifting for different values of \( T_1 \) or \( T_2 \). Most of these \( \Delta E_Z \) values are chosen to be large in order to minimize the impact caused by the Stark shift between the points where \( \Gamma_{\text{blockade}} \) and \( \Delta E_Z \) are measured. These are used to find the most suited \( T_1 \) and \( T_2 \) values that fit the data accurately [the vertical black dashed lines in (b)].

![FIG. 3. Numerical model for the blockade lifting. (a) For an initial state \( |\psi(t = 0)\rangle = |T_0(1, 1)\rangle \), the probability as a function of time \( p(t) = |\langle T_0(1, 1) |\psi(t)\rangle|^2 \) is calculated numerically using Eqs. (A1), (A2), and (A4), including dephasing processes only. The blockade rate \( \Gamma_{\text{blockade}} \) can be extracted from the decay (red dashed line). Comparison between all three plots shows that the decay rate is not monotonically dependent on the dephasing time \( T_2 \). (b) The extracted decay rates \( \Gamma_{\text{blockade}} \) as a function of charge relaxation and dephasing calculated from the simulation for four values of \( \Delta E_Z \) (blue). The values of \( \Gamma_{\text{blockade}} \) that correspond to \( \Delta E_Z \) from the experimental data (black dashed lines) are then used to extract the relaxation and dephasing times. These are \( T_2 = 0.2 \text{ ns} \) and \( T_1 = 0.15 \mu s \). For small values of \( T_2 \) and \( T_1 \), the blockade lifting is halted [37]. (c) The comparison of \( \Gamma_{\text{blockade}} \) and \( \Delta E_Z \) for the experiment (black dots) against the numerical (squares) and analytical (solid line) theoretical decay processes adopting \( T_2 = 0.2 \text{ ns} \) (red) or \( T_1 = 0.15 \mu s \) (green). The blue stars indicate the sampled points used to match the relaxation and dephasing times in (b).]
lines in Fig. 3(b)]. From the simulations \( T_2^{\text{charge}} = 0.2 \text{ ns} \) and \( T_1^{\text{charge}} = 0.15 \mu\text{s} \) are found to most accurately fit the data.

We note that when the charge relaxation or dephasing become very fast, the rate of blockade lifting \( \Gamma_{\text{blockade}} \) starts to decrease. The root of this nonmonotonic behavior is interpreted as a decoherence-based freezing of the quantum states akin to the quantum Zeno effect [37], where the Hamiltonian dynamics are halted. We do not consider these smaller values of \( T_1 \) and \( T_2 \) since they are not physical, and this regime is not achieved in the experiments presented here.

Values for charge dephasing are found experimentally to range from 0.127 to 0.760 ns for a charge qubit in a Si/SiGe heterostructure [38]. This is in agreement with \( T_2^{\text{charge}} \) found in the present work. The relaxation time of a charge qubit in another Si/SiGe device is found to vary depending on the detuning and tunnel rates of the system as well as the geometry of the double quantum dot [35]. Assuming the same analysis extends to MOS devices, the expected \( T_1^{\text{charge}} \) values should be on the order of 10 ms, which would be 4 orders of magnitude larger than the value that fits our experimental data. One cannot completely rule out the relatively short \( T_1^{\text{charge}} \) concluded here without a direct measurement. Several nonidealties could impact the real relaxation time in our device, such as oxide imperfections, piezoelectric phonons in silicon dioxide and the complications deriving from the additional electrons in our dots. To confirm this, a direct measurement of \( T_1^{\text{charge}} \) and \( T_2^{\text{charge}} \) should be done for a similar device to the one in the present work. This is not possible with our current experimental setup, which relies on subgigahertz filtering of electric noise.

For the \( T_1^{\text{charge}} \) and \( T_2^{\text{charge}} \) values found, the rate of blockade lifting \( \Gamma_{\text{blockade}} \) is calculated as a function of the Zeeman energy difference \( \Delta E_Z \). This is plotted along side the experimental \( \Gamma_{\text{blockade}} \) times in Fig. 3(c). The dephasing and relaxation processes both explain the nonlinear relationship between \( \Gamma_{\text{blockade}} \) and \( \Delta E_Z \). In contrast, only relaxation processes matter in GaAs dots [39]. This is because the singlet states are now coupled not only by the tunnel coupling, but also through the charge-oscillation decay mechanism.

V. ANALYTICAL METHOD

The quantitative agreement between the model and the experimental results confirms that our interpretation is now complete. We now steer away from numerical simulations and treat the problem analytically. The analytical method gives insight into why the decay rate depends so strongly on the Zeeman energy difference. We can now try to leverage this understanding to design readout schemes that maximize the fidelity of either parity or singlet-triplet readout, depending on the application intended.

The Schrieffer-Wolff (SW) perturbation theory [25] is chosen to study the rate at which the \( |T_0(1, 1)\rangle \) blockade is lifted, the derivation is found in the appendix. From this, two analytical equations are found to describe \( \Gamma_{\text{blockade}} \) as a function of the system parameters. When \( \Delta E_Z \) is small the rate becomes, for dephasing effects

\[
\Gamma_{\text{blockade}} \approx \frac{2\Delta E_Z^2 t^2 + \varepsilon^2}{T_2^{\text{charge}}}.
\]

and for relaxation effects,

\[
\Gamma_{\text{blockade}} \approx \frac{2\Delta E_Z^2 t^2 + \varepsilon^2}{T_1^{\text{charge}}}.
\]

It should be noted that \( T_2^{\text{charge}} \) is dependent on \( \varepsilon \) when \( \varepsilon \) is comparable or smaller than \( t \). In experiments \( T_2^{\text{charge}} \) is not controllable, but by adjusting the magnetic field of the system \( \Delta E_Z \) can be changed. This can be limited, however, since spin-orbit effects might impact other aspects of the qubit control. In that case, one would focus on the electrically controllable \( t \) and \( \varepsilon \).

Comparison between the numerical simulation results for \( \Gamma_{\text{blockade}} \) and the analytical expression, Eq. (1), is shown in Fig. 4. In the regime where \( \Delta E_Z > J \) the SW analysis fails due to the assumption of small splitting between the singlet and triplet subspaces needed for the approximation, as mentioned above. Failure of the approximation is also seen at \( \Delta E_Z \ll J \) where the nonunitary nature of the system starts to become dominant. This means that the SW method should be adjusted to incorporate the nonunitary evolution [40].

VI. DISCUSSION

At first sight, the parity-readout scheme may seem to be unable to provide the same level of information as the individual measurements of each spin qubit. This concern is already present with traditional singlet-triplet blockade readout—the outcome of the readout is a single bit of information (either the electron tunneled through or it did not), while the input is two qubits.

Measurements on single qubits based on tunneling to a large reservoir [41], however, may be impractical for a dense two-dimensional array of qubits in a large-scale quantum computer. This means that the latched readout scheme that we use as a tool to freeze the spin dynamics in our work cannot be used in a scalable architecture. This highlights the significance of parity or singlet-triplet readout, meaning the physics of singlet-triplet blockade and the onset of parity readout need to be well understood and controllably reproduced. Some of the previous literature was dedicated to recovering the most useful protocols
for quantum computing using exclusively singlet-triplet readout [42]. We describe next two examples that can be adapted for the case of a parity readout; namely, the two-qubit state tomography and the syndrome measurements in a quantum-error correction protocol.

A. Two-qubit state tomography with parity readout

State tomography relies on preparing a large ensemble (usually a time ensemble) of nominally identical qubit states and measuring them in different basis sets. In practice, direct measurements in different basis sets is impractical, so the measurement axis is kept fixed and the qubits are manipulated to map the different elements of their density matrices into probabilities of measuring certain outcomes in the fixed basis.

In this sense, universal control of these qubits is always necessary for performing quantum state tomography. The fact that a parity measurement only provides one bit of information as an output is not a significant limitation—it only means that a larger ensemble needs to be measured in order to obtain all the information in the density matrices. The practical steps to do so using singlet-triplet readout were discussed in Ref. [42].

The projection operator associated with an odd outcome of the parity readout is

$$\Pi_{\text{odd}} = \frac{1}{2} \left( \sigma_0 \otimes 1 - \sigma_y \otimes \sigma_y \right),$$

where $\sigma_0$ is the 2 × 2 identity matrix and the $\sigma_i$ denote the Pauli matrices. In order to completely reconstruct a two-qubit density operator, the state tomography requires 15 different measurement projections. Given the quantum gates that we have for our qubits, the natural choice for the projections are

$$\Pi_{MN} = \frac{1}{2} \left( I \otimes I - \sigma_M \otimes \sigma_N \right),$$

where $\Pi_{MN}$ are linearly independent projection matrices with indices $M, N \in \{I, X, Y, Z\}$. The cases when neither $M$ or $N$ are the identity can be trivially obtained by single-qubit rotations, projecting the $X$ or $Y$ components of the spin into the the $Z$ quantization axis before measuring the parity. In the cases where we want to measure a single qubit, which means that either $M$ or $N$ are the identity $I$, it is necessary to perform a controlled NOT (CNOT) operation between the two qubits before the parity readout.

The estimated density matrix $\hat{\rho}$ can then be reconstructed using

$$p_{MN} = \text{Tr}[\Pi_{MN} \hat{\rho}],$$

where $p_{MN}$ are the measurement outcomes (probabilities).

B. Quantum error detection

A universal quantum computer with error correction will require a large number of physical qubits and highly accurate measurements of these qubits in order to identify possible errors in the computation. Silicon spin qubits in CMOS devices are small enough that they may be scaled up using the mass-production techniques inherited from the transistor industry, but a scalable strategy for reading out each of the physical single-spin qubits is challenging. Instead, two spins in a double quantum dot can be used as an ancilla system to detect errors in a logical qubit.

This idea has been studied in the context of singlet-triplet readout, showing that the surface code implementation can be recovered in a reasonably direct way [18]. Demonstrating the extension of this analysis to the case of parity readout is trivial. Instead, here we focus on the time scale of the measurements.

The readout time must be much faster than the time it takes for an error to occur. A conservative bound for this time would be the spin coherence time in an echo experiment, which is typically of the order of tens or hundreds of $\mu$s. In that case, for a measurement setup similar to ours, one would be able to achieve high-fidelity singlet-triplet readout. But, as shown by Eq. (1), a larger Zeeman splitting difference could result in a measurement that is transitioning between the singlet-triplet regime and the parity regime. In this case, the fidelity of the readout would be compromised. A perhaps counter-intuitive conclusion of our analysis is that by reducing the tunnel rate one might be able to speed up the $T_0$ blockade lifting so that the readout time falls comfortably within the parity-readout range and the fidelity is improved. In order to understand the necessary range of tunnel-rate control necessary to compensate...
for typical differences in the Zeeman energy, one can compare the systems in Refs. [43] and [44], which differ in $\Delta E_Z$ by 2 orders of magnitude. In the former, $\Delta E_Z = 0.41 \text{ MHz}$ [43] so that the tunnel rate should be below 0.14 GHz to be in the parity-readout regime, while for the latter the Zeeman energy difference $\Delta E_Z = 17 \text{ MHz}$ sets the transition to be at a tunnel rate of 17 GHz. These values are estimated assuming all other parameters to be the same as in the present work [the chosen wait time, $1/\Gamma_{\text{blockade}}$, is 100 $\mu$s, which is typical for direct current single-electron transistor (DC SET) current measurements] and we adopt Eq. (1). The tunnel-coupling values calculated here correspond to the maximum tunnel coupling the system should have to remain in the parity-readout regime. This means that if both systems studied here had a tunnel coupling of 0.14 GHz, they would both exhibit parity readout. The ability to control tunnel coupling by orders of magnitude has been demonstrated using exchange-gate electrodes in quantum-dot systems in a variety of material systems [16,36,45,46].

It is then possible to lower the tunnel rate of all dot pairs in a large system to guarantee that all readout regimes are in parity mode. Potentially the opposite could also be true, depending on how achievable a large enough tunnel coupling is, given the effectiveness of the exchange-gate electrodes and the interdot distances.

C. Summary

The device studied here allows us to combine traditional Pauli blockade and latched spin readout to investigate the physical origins of the parity readout. We describe this process in terms of a model that includes both the effects of Zeeman energy difference, as well as the nonunitary charge evolution under the environment-induced noise. We investigate the model numerically and also analytically, using first-order perturbation theory, to establish an analytical formula connecting the $|T_0\rangle$ blockade rate with the detuning at the readout point $\epsilon$, the interdot tunnel rate $t$, the difference in Zeeman splittings $\Delta E_Z$, and either the charge-dephasing time $T_2^{\text{charge}}$ or the charge relaxation time $T_1^{\text{charge}}$. According to our conclusions, high-precision two-qubit state tomography is viable with this readout scheme. We also show the pathway for engineering the blockade rate for high-fidelity syndrome estimation in a quantum error-correction code, revealing that control over the tunnel rate and detuning at the readout point can compensate the Zeeman energy difference.

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APPENDIX: METHODS

1. Numerical model

The model Hamiltonian includes the tunnel coupling $t$ between the singlet states and the mixing of the $|T_0(1,1)\rangle$ and $|S(0,2)\rangle$ through the $|S(1,1)\rangle$ state, and the coupling between the $|S(1,1)\rangle$ and $|T_0(1,1)\rangle$ states because of the difference of Zeeman energies between the dots. In the basis $\{|S(0,2)\rangle, |S(1,1)\rangle, |T_0(1,1)\rangle\}$ our Hamiltonian is

$$\hat{H} = \begin{pmatrix} -\epsilon & t & 0 \\ t & 0 & \Delta E_Z \\ 0 & \Delta E_Z & 0 \end{pmatrix},$$

where $\epsilon$ is the detuning between the dots.

We study the impact of noise on the system by simulating the time evolution of the density matrix $\hat{\rho}$ as a master equation in the Lindbladian form [32,33]

$$\frac{d\hat{\rho}}{dt} = -i[\hat{H}, \hat{\rho}] + \hat{L}[\hat{a}](\hat{\rho}).$$

The Lindblad superoperator $\hat{L}[\hat{a}](\hat{\rho})$ acts on $\hat{\rho}$, describing the nonunitary evolution of the open quantum system under an assumed Markovian noise. The operator $\hat{a}$ is a jump operator chosen to model the impact of the environment on the quantum system—either a dephasing channel, which is a consequence of charge noise, or a phonon-mediated relaxation channel. The Lindblad superoperator part of the master equation can be expanded as

$$\hat{L}[\hat{a}](\hat{\rho}) = \hat{a}\hat{\rho}\hat{a}^\dagger - \frac{1}{2}(\hat{a}\hat{a}^\dagger\hat{\rho} + \hat{\rho}\hat{a}\hat{a}^\dagger).$$

Using frequency units, Eq. (A3) can be used to describe charge dephasing, $\hat{a}_{\text{dephasing}}$, and charge relaxation.
processes, \( \hat{a}_{\text{relaxation}} \), using

\[
\hat{a}_{\text{dephasing}} = \begin{pmatrix}
\frac{1}{\sqrt{2T_2}} & 0 & 0 \\
0 & -\frac{1}{\sqrt{2T_2}} & 0 \\
0 & 0 & -\frac{1}{\sqrt{2T_2}}
\end{pmatrix}, \quad (A4)
\]

or

\[
\hat{a}_{\text{relaxation}} = \begin{pmatrix}
0 & \frac{1}{\sqrt{T_1}} & 0 \\
0 & 0 & 0 \\
0 & 0 & 0
\end{pmatrix}. \quad (A5)
\]

The operator \( \hat{a}_{\text{dephasing}} \) models the phase noise acting on the charge states (1,1) and (0,2) charge states. The operator \( \hat{a}_{\text{relaxation}} \) models the depopulation of |S(1,1)⟩ relaxing into the |S(0,2)⟩ state.

2. Analytical model

We adopt quasigenerate perturbation theory [25] to study the dynamics of the |T₀⟩ unblocking as a leakage into the singlet sector of the total three-dimensional Hilbert space. For this approach to be valid, all off-diagonal terms in the Hamiltonian must be small compared to the splitting between the triplet and the singlet sectors. To ensure this condition is satisfied even when \( t \) is comparable to \( \varepsilon \), a unitary transformation is used to bring the Hamiltonian to a basis with symmetric and antisymmetric singlet-state combinations. To achieve this partial diagonalization, the unitary transformation \( \hat{U} \hat{H}_0 \hat{U} \) is performed, with a suitable choice of \( \hat{U} \)

\[
\hat{U} = \begin{pmatrix}
\frac{1}{\sqrt{2}} & \frac{1}{\sqrt{2}} & 0 \\
\frac{1}{\sqrt{2}} & -\frac{1}{\sqrt{2}} & 0 \\
0 & 0 & 1
\end{pmatrix}, \quad (A6)
\]

to give

\[
\hat{H}' = \begin{pmatrix}
\frac{-\varepsilon}{2} + \sqrt{\frac{\varepsilon^2}{4} + \frac{\Delta E_Z^2}{T_2}} & 0 & \Delta_{S-T_0}^{\text{antisym}} \\
0 & \frac{-\varepsilon}{2} - \sqrt{\frac{\varepsilon^2}{4} + \frac{\Delta E_Z^2}{T_2}} & \Delta_{S-T_0}^{\text{sym}} \\
\Delta_{S-T_0}^{\text{antisym}} & \Delta_{S-T_0}^{\text{sym}} & 0
\end{pmatrix}, \quad (A7)
\]

where

\[
\Delta_{S-T_0}^{\text{antisym}} = \frac{\Delta E_Z(\varepsilon + \sqrt{4\varepsilon^2 + \Delta E_Z^2})}{\sqrt{8\varepsilon^2 + 2\varepsilon(\varepsilon + \sqrt{4\varepsilon^2 + \Delta E_Z^2})}}, \quad (A8)
\]

and

\[
\Delta_{S-T_0}^{\text{sym}} = \frac{\Delta E_Z(\varepsilon - \sqrt{4\varepsilon^2 + \Delta E_Z^2})}{\sqrt{8\varepsilon^2 + 2\varepsilon(\varepsilon - \sqrt{4\varepsilon^2 + \Delta E_Z^2})}}. \quad (A9)
\]

Splitting the Hamiltonian into the sum

\[
\hat{H} = \hat{H}_0 + \hat{H}_1 + \hat{H}_2, \quad (A10)
\]

one can now determine the unitary operator \( e^{\hat{S}} \) that approximately diagonalizes the Hamiltonian to first order in the small perturbations \( \Delta_{S-T_0}^{\text{antisym}} \) and \( \Delta_{S-T_0}^{\text{sym}} \) following the usual SW algorithm.

We are more interested in the damping of \( |T_0⟩ \) population introduced by the Lindblad superoperator. We use the fact that the Lindbladian equation is invariant under unitary transformations and obtain the transformed quantum channel

\[
\hat{\sigma}' = e^{-\hat{S}\hat{U}} e^{\hat{S}} . \quad (A11)
\]

This enables us to find the damping of \( |T_0⟩ \) as a function of the system parameters by looking at the resulting dynamical equation for \( \rho_{T_0} = \langle T_0(1,1)|\hat{\rho}|T_0(1,1)⟩ \). The general form for this equation is

\[
\frac{d\rho_{T_0}}{dt} = -\Gamma_{\text{blockade}} \rho_{T_0} + C, \quad (A12)
\]

where \( C \) stands for the terms that are not proportional to \( -\rho_{T_0} \), and therefore are not responsible for damping.

Substituting Eqs. (A11) and (A12), for the dephasing jump operator (A4), into the master Eq. (A3) and looking at the \( \rho_{T_0} \) elements only, the analytical expression is found,

\[
\Gamma_{\text{blockade}} \approx \frac{2\rho^2}{T_2^{\text{charge}}} \sin \left( \frac{\Delta E_Z \sqrt{T^2 + \varepsilon^2}}{T^2} \right)^2. \quad (A13)
\]

This expression is useful because it gives us insight into how to control \( \Gamma_{\text{blockade}} \). Specifically, when \( \Delta E_Z \) is small, Eq. (A13) becomes

\[
\Gamma_{\text{blockade}} \approx \frac{2\Delta E_Z^2}{T_2^{\text{charge}}} \frac{T^2 + \varepsilon^2}{T^2 \varepsilon^2}. \quad (A14)
\]

For the case of the relaxation process, \( \Gamma_{\text{blockade}} \) is found using the same SW method and, when \( \Delta E_Z \) is small, one obtains

\[
\Gamma_{\text{blockade}} \approx \frac{2\Delta E_Z^2}{T_1^{\text{charge}}} \frac{T^2 + \varepsilon^2}{T^4}. \quad (A15)
\]


PAULI BLOCKADE IN SILICON QUANTUM DOTS...


